# 1600 (H) x 1200 (V) Interline CCD Image Sensor

## **Description**

The KAI-02050 Image Sensor is a 2-megapixel CCD in a 2/3" optical format. Based on the TRUESENSE 5.5 micron Interline Transfer CCD Platform, the sensor features broad dynamic range, excellent imaging performance, and a flexible readout architecture that enables use of 1, 2, or 4 outputs for full resolution readout up to 68 frames per second. A vertical overflow drain structure suppresses image blooming and enables electronic shuttering for precise exposure control. Other features include low dark current, negligible lag, and low smear.

The sensor shares common PGA pin-out and electrical configurations with other devices based on the TRUESENSE 5.5 micron Interline Transfer CCD Platform, allowing a single camera design to support multiple members of this sensor family.

**Table 1. GENERAL SPECIFICATIONS** 

Parameter	Typical Value
Architecture	Interline CCD, Progressive Scan
Total Number of Pixels	1684 (H) × 1264 (V)
Number of Effective Pixels	1640 (H) × 1240 (V)
Number of Active Pixels	1600 (H) × 1200 (V)
Pixel Size	5.5 μm (H) × 5.5 μm (V)
Active Image Size	8.8 mm (H) $\times$ 6.6 mm (V) 11.0 mm (diagonal), 2/3" Optical Format
Aspect Ratio	4:3
Number of Outputs	1, 2, or 4
Charge Capacity	20,000 electrons
Output Sensitivity	34 μV/e <sup>-</sup>
Quantum Efficiency Mono (–ABA) R, G, B (–FBA) R, G, B (–CBA)	44% 29%, 37%, 39% 31%, 37%, 38%
Read Noise (f = 40 MHz)	12 e <sup>-</sup> rms
Dark Current Photodiode / VCCD	7 / 100 e <sup>-</sup> /s
Dark Current Doubling Temp Photodiode / VCCD	7°C / 9°C
Dynamic Range	64 dB
Charge Transfer Efficiency	0.99999
Blooming Suppression	> 300 X
Smear	-100 dB
Image Lag	< 10 electrons
Maximum Pixel Clock Speed	40 MHz
Maximum Frame Rates Quad / Dual / Single Output	68 / 34 / 18 fps
Package	68 Pin PGA 64 Pin CLCC
Cover Glass	AR Coated, 2-Sides or Clear Glass

NOTE: All Parameters are specified at T = 40°C unless otherwise noted.



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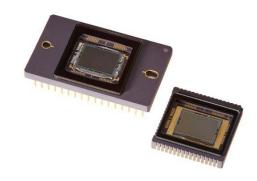


Figure 1. KAI-02050 Interline CCD Image Sensor

#### **Features**

- Color or Monochrome Configurations
- Progressive Scan Readout
- Flexible Readout Architecture
- High Frame Rate
- High Sensitivity
- Low Noise Architecture
- Excellent Smear Performance
- Package Pin Reserved for Device Identification

#### **Applications**

- Industrial Imaging
- Medical Imaging
- Security

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

## **ORDERING INFORMATION**

## **Standard Devices**

See full datasheet for ordering information associated with devices no longer recommended for new designs.

Table 2. ORDERING INFORMATION - STANDARD DEVICES

Part Number	Description	Marking Code
KAI-02050-AAA-JP-BA	Monochrome, No Microlens, PGA Package, Taped Clear Cover Glass, No Coatings, Standard Grade.	KAI-02050-AAA
KAI-02050-AAA-JP-AE	Monochrome, No Microlens, PGA Package, Taped Clear Cover Glass, No Coatings, Engineering Grade.	Serial Number
KAI-02050-ABA-JD-BA	Monochrome, Telecentric Microlens, PGA Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Standard Grade.	
KAI-02050-ABA-JD-AE	Monochrome, Telecentric Microlens, PGA Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Engineering Grade.	
KAI-02050-ABA-JP-BA	Monochrome, Telecentric Microlens, PGA Package, Taped Clear Cover Glass, No Coatings, Standard Grade.	KAI-02050-ABA
KAI-02050-ABA-JP-AE	Serial Number	
KAI-02050-ABA-FD-BA		
KAI-02050-ABA-FD-AE	Monochrome, Telecentric Microlens, CLCC Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Engineering Grade.	
KAI-02050-FBA-JD-BA	Gen2 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Standard Grade.	
KAI-02050-FBA-JD-AE	Gen2 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Engineering Grade.	KAI-02050-FBA
KAI-02050-FBA-FD-BA	Gen2 Color (Bayer RGB), Telecentric Microlens, CLCC Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Standard Grade.	Serial Number
KAI-02050-FBA-FD-AE	Gen2 Color (Bayer RGB), Telecentric Microlens, CLCC Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Engineering Grade.	
KAI-02050-FBA-JB-B2	Gen2 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2.	
KAI-02050-FBA-JB-AE	Gen2 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Engineering Grade.	KAI-02050-FBA Serial Number V <sub>AB</sub> = xx.x
KAI-02050-FBA-JB-B2-T	Gen2 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2, Packed in Trays.	Λυ .

See the ON Semiconductor *Device Nomenclature* document (TND310/D) for a full description of the naming convention used for image sensors. For reference documentation, including information on evaluation kits, please visit our web site at <a href="https://www.onsemi.com">www.onsemi.com</a>.

## **Not Recommended for New Designs**

## Table 3. ORDERING INFORMATION - NOT RECOMMENDED FOR NEW DESIGNS

Part Number	Description	Marking Code		
KAI-02050-CBA-JD-BA	Gen1 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Standard Grade.			
KAI-02050-CBA-JD-AE	KAI-02050-CBA			
KAI-02050-CBA-FD-BA	Serial Number			
KAI-02050-CBA-FD-AE	Gen1 Color (Bayer RGB), Telecentric Microlens, CLCC Package, Sealed Clear Cover Glass with AR Coating (Both Sides), Engineering Grade.			
KAI-02050-CBA-JB-B2	Gen1 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2.			
KAI-02050-CBA-JB-AE	Gen1 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Engineering Grade.	KAI-02050-CBA Serial Number V <sub>AB</sub> = xx.x		
KAI-02050-CBA-JB-B2-T	Gen1 Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2, Packed in Trays.	- AD		

#### **DEVICE DESCRIPTION**

#### **Architecture**

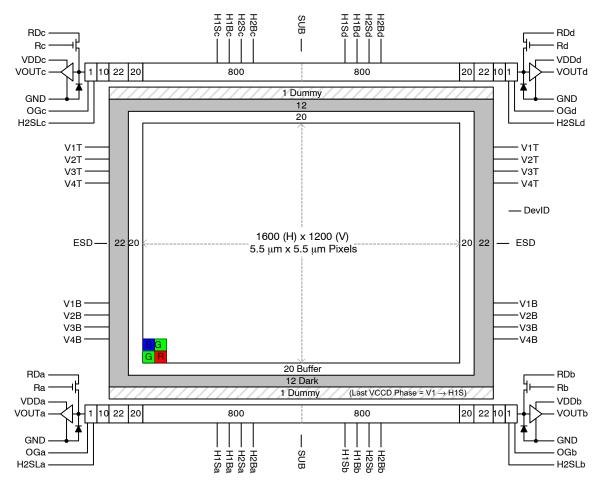


Figure 2. Block Diagram

## **Dark Reference Pixels**

There are 12 dark reference rows at the top and 12 dark rows at the bottom of the image sensor. The dark rows are not entirely dark and so should not be used for a dark reference level. Use the 22 dark columns on the left or right side of the image sensor as a dark reference.

Under normal circumstances use only the center 20 columns of the 22 column dark reference due to potential light leakage.

## **Dummy Pixels**

Within each horizontal shift register there are 11 leading additional shift phases. These pixels are designated as dummy pixels and should not be used to determine a dark reference level.

In addition, there is one dummy row of pixels at the top and bottom of the image.

#### **Active Buffer Pixels**

20 unshielded pixels adjacent to any leading or trailing dark reference regions are classified as active buffer pixels.

These pixels are light sensitive but are not tested for defects and non-uniformities.

#### **Image Acquisition**

An electronic representation of an image is formed when incident photons falling on the sensor plane create electron-hole pairs within the individual silicon photodiodes. These photoelectrons are collected locally by the formation of potential wells at each photosite. Below photodiode saturation, the number of photoelectrons collected at each pixel is linearly dependent upon light level and exposure time and non-linearly dependent on wavelength. When the photodiodes charge capacity is reached, excess electrons are discharged into the substrate to prevent blooming.

#### **ESD Protection**

Adherence to the power-up and power-down sequence is critical. Failure to follow the proper power-up and power-down sequences may cause damage to the sensor. See Power-Up and Power-Down Sequence section.

## **Physical Description**

PGA Pin Description and Device Orientation

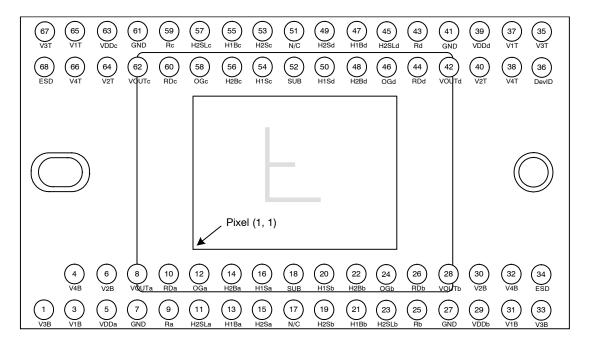


Figure 3. PGA Package Pin Designations - Top View

**Table 4. PGA PACKAGE PIN DESCRIPTION** 

Pin	Name	Description
1	V3B	Vertical CCD Clock, Phase 3, Bottom
3	V1B	Vertical CCD Clock, Phase 1, Bottom
4	V4B	Vertical CCD Clock, Phase 4, Bottom
5	VDDa	Output Amplifier Supply, Quadrant a
6	V2B	Vertical CCD Clock, Phase 2, Bottom
7	GND	Ground
8	VOUTa	Video Output, Quadrant a
9	Ra	Reset Gate, Quadrant a
10	RDa	Reset Drain, Quadrant a
11	H2SLa	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant a
12	OGa	Output Gate, Quadrant a
13	H1Ba	Horizontal CCD Clock, Phase 1, Barrier, Quadrant a
14	H2Ba	Horizontal CCD Clock, Phase 2, Barrier, Quadrant a
15	H2Sa	Horizontal CCD Clock, Phase 2, Storage, Quadrant a
16	H1Sa	Horizontal CCD Clock, Phase 1, Storage, Quadrant a
17	N/C	No Connect
18	SUB	Substrate
19	H2Sb	Horizontal CCD Clock, Phase 2, Storage, Quadrant b
20	H1Sb	Horizontal CCD Clock, Phase 1, Storage, Quadrant b
21	H1Bb	Horizontal CCD Clock, Phase 1, Barrier, Quadrant b
22	H2Bb	Horizontal CCD Clock, Phase 2, Barrier, Quadrant b
23	H2SLb	Horizontal CCD Clock, Phase 1, Storage, Last Phase, Quadrant b
24	OGb	Output Gate, Quadrant b

Table 4. PGA PACKAGE PIN DESCRIPTION (continued)

Pin	Name	Description
25	Rb	Reset Gate, Quadrant b
26	RDb	Reset Drain, Quadrant b
27	GND	Ground
28	VOUTb	Video Output, Quadrant b
29	VDDb	Output Amplifier Supply, Quadrant b
30	V2B	Vertical CCD Clock, Phase 2, Bottom
31	V1B	Vertical CCD Clock, Phase 1, Bottom
32	V4B	Vertical CCD Clock, Phase 4, Bottom
33	V3B	Vertical CCD Clock, Phase 3, Bottom
34	ESD	ESD Protection Disable
35	V3T	Vertical CCD Clock, Phase 3, Top
36	DevID	Device Identification
37	V1T	Vertical CCD Clock, Phase 1, Top
38	V4T	Vertical CCD Clock, Phase 4, Top
39	VDDd	Output Amplifier Supply, Quadrant d
40	V2T	Vertical CCD Clock, Phase 2, Top
41	GND	Ground
42	VOUTd	Video Output, Quadrant d
43	Rd	Reset Gate, Quadrant d
44	RDd	Reset Drain, Quadrant d
45	H2SLd	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant d
46	OGd	Output Gate, Quadrant d
47	H1Bd	Horizontal CCD Clock, Phase 1, Barrier, Quadrant d
48	H2Bd	Horizontal CCD Clock, Phase 2, Barrier, Quadrant d
49	H2Sd	Horizontal CCD Clock, Phase 2, Storage, Quadrant d
50	H1Sd	Horizontal CCD Clock, Phase 1, Storage, Quadrant d
51	N/C	No Connect
52	SUB	Substrate
53	H2Sc	Horizontal CCD Clock, Phase 2, Storage, Quadrant c
54	H1Sc	Horizontal CCD Clock, Phase 1, Storage, Quadrant c
55	H1Bc	Horizontal CCD Clock, Phase 1, Barrier, Quadrant c
56	H2Bc	Horizontal CCD Clock, Phase 2, Barrier, Quadrant c
57	H2SLc	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant c
58	OGc	Output Gate, Quadrant c
59	Rc	Reset Gate, Quadrant c
60	RDc	Reset Drain, Quadrant c
61	GND	Ground
62	VOUTc	Video Output, Quadrant c
63	VDDc	Output Amplifier Supply, Quadrant c
64	V2T	Vertical CCD Clock, Phase 2, Top
65	V1T	Vertical CCD Clock, Phase 1, Top
66	V4T	Vertical CCD Clock, Phase 4, Top
67	V3T	Vertical CCD Clock, Phase 3, Top
68	ESD	EDS Protection Disable

Liked named pins are internally connected and should have a common drive signal.
 N/C pins (17, 51) should be left floating.

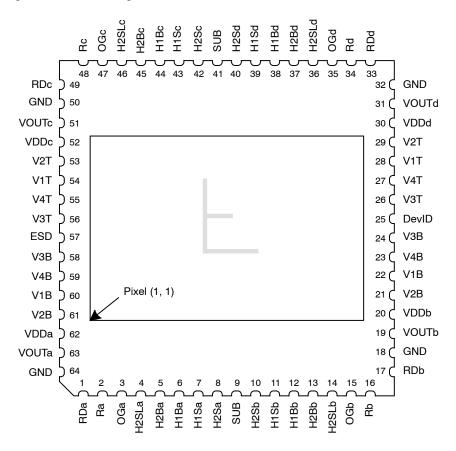


Figure 4. CLCC Package Pin Designations - Top View

**Table 5. CLCC PACKAGE PIN DESCRIPTION** 

Pin	Name	Description
1	RDa	Reset Drain, Quadrant a
2	Ra	Reset Gate, Quadrant a
3	OGa	Output Gate, Quadrant a
4	H2SLa	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant a
5	H2Ba	Horizontal CCD Clock, Phase 2, Barrier, Quadrant a
6	H1Ba	Horizontal CCD Clock, Phase 1, Barrier, Quadrant a
7	H1Sa	Horizontal CCD Clock, Phase 1, Storage, Quadrant a
8	H2Sa	Horizontal CCD Clock, Phase 2, Storage, Quadrant a
9	SUB	Substrate
10	H2Sb	Horizontal CCD Clock, Phase 2, Storage, Quadrant b
11	H1Sb	Horizontal CCD Clock, Phase 1, Storage, Quadrant b
12	H1Bb	Horizontal CCD Clock, Phase 1, Barrier, Quadrant b
13	H2Bb	Horizontal CCD Clock, Phase 2, Barrier, Quadrant b
14	H2SLb	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant b
15	OGb	Output Gate, Quadrant b
16	Rb	Reset Gate, Quadrant b
17	RDb	Reset Drain, Quadrant b
18	GND	Ground
19	VOUTb	Video Output, Quadrant b

Table 5. CLCC PACKAGE PIN DESCRIPTION (continued)

Pin	Name	Description
20	VDDb	Output Amplifier Supply, Quadrant b
21	V2B	Vertical CCD Clock, Phase 2, Bottom
22	V1B	Vertical CCD Clock, Phase 1, Bottom
23	V4B	Vertical CCD Clock, Phase 4, Bottom
24	V3B	Vertical CCD Clock, Phase 3, Bottom
25	DevID	Device Identification
26	V3T	Vertical CCD Clock, Phase 3, Top
27	V4T	Vertical CCD Clock, Phase 4, Top
28	V1T	Vertical CCD Clock, Phase 1, Top
29	V2T	Vertical CCD Clock, Phase 2, Top
30	VDDd	Output Amplifier Supply, Quadrant d
31	VOUTd	Video Output, Quadrant d
32	GND	Ground
33	RDd	Reset Drain, Quadrant d
34	Rd	Reset Gate, Quadrant d
35	OGd	Output Gate, Quadrant d
36	H2SLd	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant d
37	H2Bd	Horizontal CCD Clock, Phase 2, Barrier, Quadrant d
38	H1Bd	Horizontal CCD Clock, Phase 1, Barrier, Quadrant d
39	H1Sd	Horizontal CCD Clock, Phase 1, Storage, Quadrant d
40	H2Sd	Horizontal CCD Clock, Phase 2, Storage, Quadrant d
41	SUB	Substrate
42	H2Sc	Horizontal CCD Clock, Phase 2, Storage, Quadrant c
43	H1Sc	Horizontal CCD Clock, Phase 1, Storage, Quadrant c
44	H1Bc	Horizontal CCD Clock, Phase 1, Barrier, Quadrant c
45	H2Bc	Horizontal CCD Clock, Phase 2, Barrier, Quadrant c
46	H2SLc	Horizontal CCD Clock, Phase 2, Storage, Last Phase, Quadrant c
47	OGc	Output Gate, Quadrant c
48	Rc	Reset Gate, Quadrant c
49	RDc	Reset Drain, Quadrant c
50	GND	Ground
51	VOUTc	Video Output, Quadrant c
52	VDDc	Output Amplifier Supply, Quadrant c
53	V2T	Vertical CCD Clock, Phase 2, Top
54	V1T	Vertical CCD Clock, Phase 1, Top
55	V4T	Vertical CCD Clock, Phase 4, Top
56	V3T	Vertical CCD Clock, Phase 3, Top
57	ESD	ESD Protection Disable
58	V3B	Vertical CCD Clock, Phase 3, Bottom
59	V4B	Vertical CCD Clock, Phase 4, Bottom
60	V1B	Vertical CCD Clock, Phase 1, Bottom
61	V2B	Vertical CCD Clock, Phase 2, Bottom
62	VDDa	Output Amplifier Supply, Quadrant a
63	VOUTa	Video Output, Quadrant a
64	GND	Ground

<sup>1.</sup> Liked named pins are internally connected and should have a common drive signal.

## **IMAGING PERFORMANCE**

## **Typical Operational Conditions**

Unless otherwise noted, the Imaging Performance Specifications are measured using the following conditions.

## **Table 6. TYPICAL OPERATIONAL CONDITIONS**

Description	Condition	Notes
Light Source	Continuous Red, Green and Blue LED Illumination.	For monochrome sensor, only green LED used.
Operation	Nominal Operating Voltages and Timing.	

## **Specifications**

## **Table 7. PERFORMANCE SPECIFICATIONS**

Description	Symbol	Min.	Nom.	Max.	Unit	Sampling Plan	Temperature Tested at (°C)
ALL CONFIGURATIONS	•		•		1	•	•
Dark Field Global Non-Uniformity	DSNU	-	-	2.0	mVpp	Die	27, 40
Bright Field Global Non-Uniformity (Note 1)		-	2.0	5.0	% rms	Die	27, 40
Bright Field Global Peak to Peak Non-Uniformity (Note 1)	PRNU	-	5.0	15.0	% pp	Die	27, 40
Bright Field Center Non-Uniformity (Note 1)		-	1.0	2.0	% rms	Die	27, 40
Maximum Photoresponse Non-Linearity (Note 2)	NL	-	2	-	%	Design	
Maximum Gain Difference between Outputs (Note 2)	ΔG	-	10	-	%	Design	
Maximum Signal Error due to Non-Linearity Differences (Note 2)	ΔNL	-	1	-	%	Design	
Horizontal CCD Charge Capacity	H <sub>Ne</sub>	-	55	-	ke-	Design	
Vertical CCD Charge Capacity	V <sub>Ne</sub>	-	45	-	ke-	Design	
Photodiode Charge Capacity (Note 3)	P <sub>Ne</sub>	-	20	-	ke-	Die	27, 40
Horizontal CCD Charge Transfer Efficiency	HCTTE	0.999995	0.999999	-		Die	
Vertical CCD Charge Transfer Efficiency	VCTE	0.999995	0.999999	-		Die	
Photodiode Dark Current	I <sub>PD</sub>	-	7	70	e/p/s	Die	40
Vertical CCD Dark Current	I <sub>VD</sub>	-	100	300	e/p/s	Die	40
Image Lag	Lag	-	-	10	e-	Design	
Anti-Blooming Factor	X <sub>AB</sub>	300	-	-		Design	
Vertical Smear	Smr	-	-100	-	dB	Design	
Read Noise (Note 4)	n <sub>e-T</sub>	-	12	-	e⁻ rms	Design	
Dynamic Range (Notes 4, 5)	DR	-	64	-	dB	Design	
Output Amplifier DC Offset	V <sub>ODC</sub>	-	9.4	-	V	Die	27, 40
Output Amplifier Bandwidth (Note 6)	f <sub>-3db</sub>	-	250	-	MHz	Die	
Output Amplifier Impedance	R <sub>OUT</sub>	-	127	-	Ω	Die	27, 40
Output Amplifier Sensitivity	ΔV/ΔΝ	-	34	-	μV/e <sup>-</sup>	Design	

Table 7. PERFORMANCE SPECIFICATIONS (continued)

Description	Symbol	Min.	Nom.	Max.	Unit	Sampling Plan	Temperature Tested at (°C)
KAI-02050-ABA CONFIGURATION	1			I.	- N	ı	l
Peak Quantum Efficiency	QE <sub>MAX</sub>	-	44	_	%	Design	
Peak Quantum Efficiency Wavelength	λQE	-	480	-	nm	Design	
KAI-02050-FBA GEN2 COLOR CONFIG	URATION W	ITH MAR GL	ASS	•	•	1	
Peak Quantum Efficiency Blue Green Red	QE <sub>MAX</sub>	- - -	38 37 31	- - -	%	Design	
Peak Quantum Efficiency Wavelength Blue Green Red	λQE	- - -	460 530 605	- - -	nm	Design	
KAI-02050-CBA GEN1 COLOR CONFIC	URATION W	ITH MAR GL	ASS (Note 7	)			
Peak Quantum Efficiency Blue Green Red	QE <sub>MAX</sub>	- - -	39 37 29	- - -	%	Design	
Peak Quantum Efficiency Wavelength Blue Green Red	λQE	- - -	470 540 620	- - -	nm	Design	
KAI-02050-FBA GEN2 COLOR CONFIG	URATION W	TH CLEAR	GLASS				
Peak Quantum Efficiency Blue Green Red	QE <sub>MAX</sub>	- - -	35 34 29	- - -	%	Design	
Peak Quantum Efficiency Wavelength Blue Green Red	λQE	- - -	460 530 605	- - -	nm	Design	
KAI-02050-CBA GEN1 COLOR CONFIC	URATION W	ITH CLEAR	GLASS (Note	∋ 7)			
Peak Quantum Efficiency Blue Green Red	QE <sub>MAX</sub>	- - -	36 34 27	- - -	%	Design	
Peak Quantum Efficiency Wavelength Blue Green Red	λQE	- - -	470 540 620	- - -	nm	Design	

<sup>1.</sup> Per color.

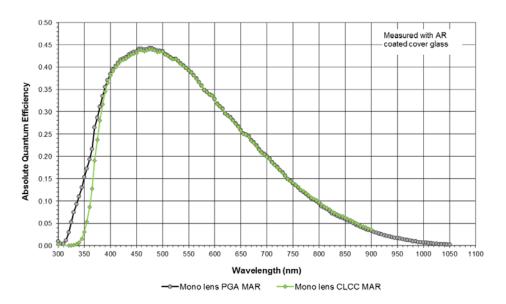
Value is over the range of 10% to 90% of photodiode saturation.
 The operating value of the substrate voltage, V<sub>AB</sub>, will be marked on the shipping container for each device. The value of V<sub>AB</sub> is set such that the photodiode charge capacity is 680 mV.

<sup>4.</sup> At 40 MHz.
5. Uses 20LOG (P<sub>Ne</sub> / n<sub>e-T</sub>).
6. Assumes 5 pF load.
7. This color filter set configuration (Gen1) is not recommended for new designs.

## **TYPICAL PERFORMANCE CURVES**

#### **Quantum Efficiency**

Monochrome with Microlens



NOTE: The PGA and CLCC versions have different quantum efficiencies due to differences in the cover glass transmission. See Figure 32: Cover Glass Transmission for more details.

Figure 5. Monochrome with Microlens Quantum Efficiency

Monochrome without Microlens

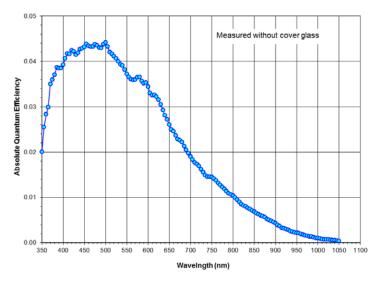


Figure 6. Monochrome without Microlens Quantum Efficiency

Color (Bayer RGB) with Microlens and MAR Cover Glass (Gen2 and Gen1 CFA)

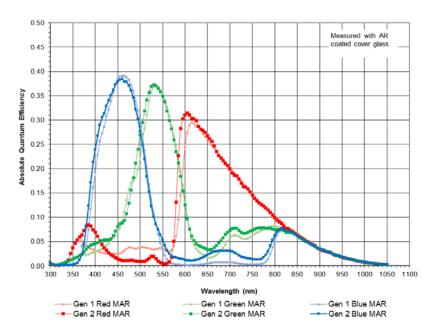


Figure 7. MAR Glass Color (Bayer) with Microlens Quantum Efficiency

Color (Bayer RGB) with Microlens and Clear Cover Glass (Gen2 and Gen1 CFA)

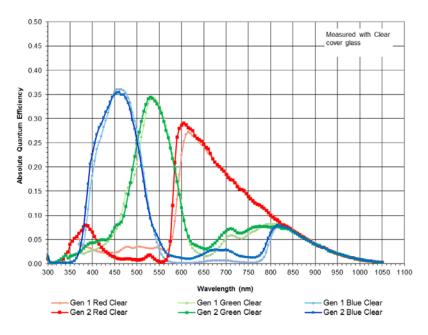


Figure 8. Clear Glass Color (Bayer) with Microlens Quantum Efficiency

## **Angular Quantum Efficiency**

For the curves marked "Horizontal", the incident light angle is varied in a plane parallel to the HCCD. For the curves marked "Vertical", the incident light angle is varied in a plane parallel to the VCCD.

Monochrome with Microlens

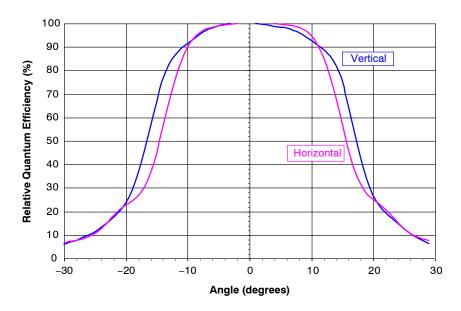


Figure 9. Monochrome with Microlens Angular Quantum Efficiency

## **Dark Current vs. Temperature**

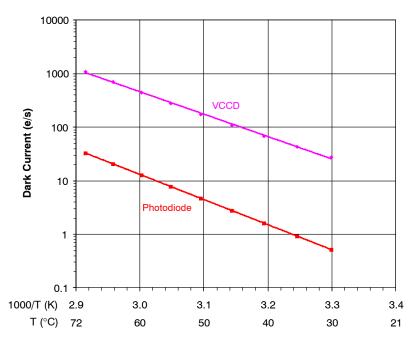


Figure 10. Dark Current vs. Temperature

## **Power-Estimated**

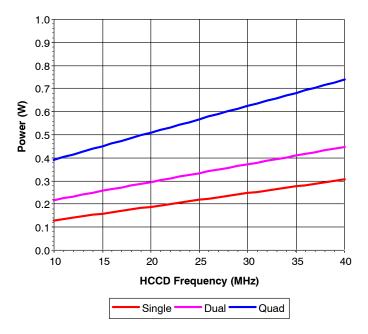


Figure 11. Power

## Frame Rates

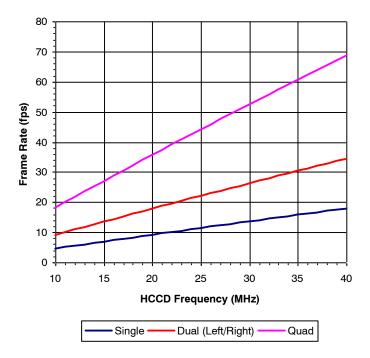


Figure 12. Frame Rates

## **DEFECT DEFINITIONS**

Table 8. OPERATION CONDITIONS FOR DEFECT TESTING AT 40°C

Description	Condition	Notes	
Operational Mode	Two Outputs, Using VOUTa and VOUTc, Continuous Readout		
HCCD Clock Frequency	10 MHz		
Pixels per Line	1840	1	
Lines per Frame	720	2	
Line Time	186.9 μs		
Frame Time	134.6 ms		
Photodiode Integration Time	Mode A: PD_Tint = Frame Time = 134.6 ms, No Electronic Shutter Used  Mode B: PD_Tint = 33 ms, Electronic Shutter Used		
VCCD Integration Time	118.1 ms	3	
Temperature	40°C		
Light Source	Continuous Red, Green and Blue LED Illumination	4	
Operation	Nominal Operating Voltages and Timing		

- Horizontal overclocking used.
   Vertical overclocking used.
- 3. VCCD Integration Time = 632 lines × Line Time, which is the total time a pixel will spend in the VCCD registers.
- 4. For monochrome sensor, only the green LED is used.

## Table 9. DEFECT DEFINITIONS FOR TESTING AT 40°C

Description	Definition	Standard Grade	Grade 2	Notes
Major Dark Field Defective Bright Pixel	PD_Tint = Mode A $\rightarrow$ Defect $\geq$ 47 mV or PD_Tint = Mode B $\rightarrow$ Defect $\geq$ 12 mV	20	20	1
Major Bright Field Defective Dark Pixel	Defect ≥ 12%	20	20	1
Minor Dark Field Defective Bright Pixel	$\begin{array}{c} \text{PD\_Tint} = \text{Mode A} \rightarrow \text{Defect} \geq 24 \text{ mV} \\ \text{or} \\ \text{PD\_Tint} = \text{Mode B} \rightarrow \text{Defect} \geq 6 \text{ mV} \end{array}$	200	200	
Cluster Defect (Standard Grade)	A group of 2 to 10 contiguous major defective pixels, but no more than 2 adjacent defects horizontally.	8	N/A	2
Cluster Defect (Grade 2)	A group of 2 to 10 contiguous major defective pixels.	N/A	8	2
Column Defect	A group of more than 10 contiguous major defective pixels along a single column.	0	0	2

<sup>1.</sup> For the color device (KAI-02050-FBA or KAI-02050-CBA), a bright field defective pixel deviates by 12% with respect to pixels of the same color.

<sup>2.</sup> Column and cluster defects are separated by no less than two (2) good pixels in any direction (excluding single pixel defects).

Table 10. OPERATION CONDITIONS FOR DEFECT TESTING AT 27°C

Description	Condition	Notes
Operational Mode	Two Outputs, Using VOUTa and VOUTc, Continuous Readout	
HCCD Clock Frequency	20 MHz	
Pixels per Line	1840	1
Lines per Frame	720	2
Line Time	93.8 μs	
Frame Time	67.5 ms	
Photodiode Integration Time (PD_Tint)	Mode A: PD_Tint = Frame Time = 67.5 ms, No Electronic Shutter Used Mode B: PD_Tint = 33 ms, Electronic Shutter Used	
VCCD Integration Time	59.3 ms	3
Temperature	27°C	
Light Source	Continuous Red, Green and Blue LED Illumination	4
Operation	Nominal Operating Voltages and Timing	

<sup>1.</sup> Horizontal overclocking used.

Table 11. DEFECT DEFINITIONS FOR TESTING AT 40°C

Description	Definition	Standard Grade	Grade 2	Notes
Major Dark Field Defective Bright Pixel	PD_Tint = Mode A $\rightarrow$ Defect $\geq$ 8 mV or PD_Tint = Mode B $\rightarrow$ Defect $\geq$ 4 mV	20	20	1
Major Bright Field Defective Dark Pixel	Defect ≥ 12%	20	20	1
Cluster Defect (Standard Grade)	A group of 2 to 10 contiguous major defective pixels, but no more than 2 adjacent defects horizontally.	8	N/A	2
Cluster Defect (Grade 2)	A group of 2 to 10 contiguous major defective pixels.	N/A	8	2
Column Defect	A group of more than 10 contiguous major defective pixels along a single column.	0	0	2

<sup>1.</sup> For the color device (KAI-02050-FBA or KAI-02050-CBA), a bright field defective pixel deviates by 12% with respect to pixels of the same color.

## **Defect Map**

The defect map supplied with each sensor is based upon testing at an ambient (27°C) temperature. Minor point defects are not included in the defect map. All defective

pixels are reference to pixel 1, 1 in the defect maps. See Figure 13: Regions of Interest for the location of pixel 1, 1.

<sup>2.</sup> Vertical overclocking used.

<sup>3.</sup> VCCD Integration Time = 632 lines × Line Time, which is the total time a pixel will spend in the VCCD registers.

<sup>4.</sup> For monochrome sensor, only the green LED is used.

<sup>2.</sup> Column and cluster defects are separated by no less than two (2) good pixels in any direction (excluding single pixel defects).

#### **TEST DEFINITIONS**

#### **Test Regions of Interest**

Image Area ROI: Pixel (1, 1) to Pixel (1640, 1240)
Active Area ROI: Pixel (21, 21) to Pixel (1620, 1220)
Center ROI: Pixel (771, 571) to Pixel (870, 670)

Only the Active Area ROI pixels are used for performance and defect tests.

#### Overclocking

The test system timing is configured such that the sensor is overclocked in both the vertical and horizontal directions. See Figure 13 for a pictorial representation of the regions of interest.

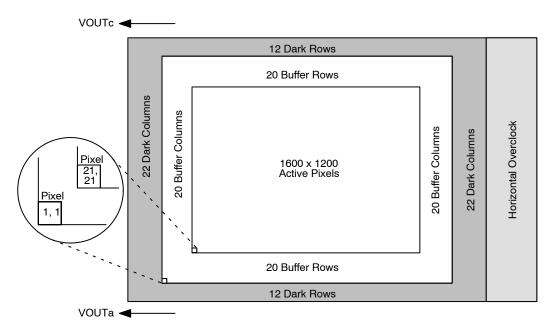


Figure 13. Regions of Interest

#### **Tests**

## Dark Field Global Non-Uniformity

This test is performed under dark field conditions. The sensor is partitioned into 192 sub regions of interest, each of which is 100 by 100 pixels in size. See Figure 14: Test Sub Regions of Interest. The average signal level of each of the 192 sub regions of interest is calculated. The signal level of each of the sub regions of interest is calculated using the following formula:

Signal of ROI[i] = (ROI Average in Counts –

- Horizontal Overclock Average in Counts) ·

· mV per Count

Units: mVpp (millivolts Peak to Peak)

Where i = 1 to 192. During this calculation on the 192 sub regions of interest, the maximum and minimum signal levels are found. The dark field global uniformity is then calculated as the maximum signal found minus the minimum signal level found.

## Global Non-Uniformity

This test is performed with the imager illuminated to a level such that the output is at 70% of saturation (approximately 476 mV). Prior to this test being performed the substrate

voltage has been set such that the charge capacity of the sensor is 680 mV. Global non-uniformity is defined as

$$\mbox{Global Non-Uniformity} \ = \ 100 \ \cdot \left( \frac{\mbox{Active Area Standard Deviation}}{\mbox{Active Area Signal}} \right)$$

Units: % rms

Active Area Signal = Active Area Average - Dark Column Average

#### Global Peak to Peak Non-Uniformity

This test is performed with the imager illuminated to a level such that the output is at 70% of saturation (approximately 476 mV). Prior to this test being performed the substrate voltage has been set such that the charge capacity of the sensor is 680 mV. The sensor is partitioned into 192 sub regions of interest, each of which is 100 by 100 pixels in size. See Figure 14: Test Sub Regions of Interest. The average signal level of each of the 192 sub regions of interest (ROI) is calculated. The signal level of each of the sub regions of interest is calculated using the following formula:

Signal of ROI[i] = (ROI Average in Counts -

- Horizontal Overclock Average in Counts) ·
- · mV per Count

Where i = 1 to 192. During this calculation on the 192 sub regions of interest, the maximum and minimum signal levels are found. The global peak to peak uniformity is then calculated as:

Global Uniformity = 
$$100 \cdot \left( \frac{\text{Max. Signal} - \text{Min. Signal}}{\text{Active Area Signal}} \right)$$

#### Center Non-Uniformity

This test is performed with the imager illuminated to a level such that the output is at 70% of saturation (approximately 476 mV). Prior to this test being performed the substrate voltage has been set such that the charge capacity of the sensor is 680 mV. Defects are excluded for the calculation of this test. This test is performed on the center 100 by 100 pixels of the sensor. Center uniformity is defined as:

$$Center \ ROI \ Uniformity \ = \ 100 \ \cdot \left( \frac{Center \ ROI \ Standard \ Deviation}{Center \ ROI \ Signal} \right)$$

Units: % rms

Center ROI Signal = Center ROI Average - Dark Colum Average

#### Dark Field Defect Test

This test is performed under dark field conditions. The sensor is partitioned into 192 sub regions of interest, each of which is 100 by 100 pixels in size. In each region of interest, the median value of all pixels is found. For each region of interest, a pixel is marked defective if it is greater than or equal to the median value of that region of interest plus the defect threshold specified in the "Defect Definitions" section.

Bright Field Defect Test

This test is performed with the imager illuminated to a level such that the output is at approximately 476 mV. Prior to this test being performed the substrate voltage has been set such that the charge capacity of the sensor is 680 mV. The average signal level of all active pixels is found. The bright and dark thresholds are set as:

Dark Defect Threshold = Active Area Signal · Threshold

Bright Defect Threshold = Active Area Signal · Threshold

The sensor is then partitioned into 192 sub regions of interest, each of which is 100 by 100 pixels in size. In each region of interest, the average value of all pixels is found. For each region of interest, a pixel is marked defective if it is greater than or equal to the median value of that region of interest plus the bright threshold specified or if it is less than or equal to the median value of that region of interest minus the dark threshold specified.

Example for major bright field defective pixels:

- Average value of all active pixels is found to be 476 mV.
- Dark defect threshold:  $476 \text{ mV} \cdot 12 \% = 57 \text{ mV}$ .
- Bright defect threshold:  $476 \text{ mV} \cdot 12 \% = 57 \text{ mV}$ .
- Region of interest #1 selected. This region of interest is pixels 21, 21 to pixels 120, 120.
  - Median of this region of interest is found to be 470 mV.
  - Any pixel in this region of interest that is
     ≥ (470 + 57 mV) 527 mV in intensity will be marked
    defective.
  - Any pixel in this region of interest that is ≤ (470 – 57 mV) 413 mV in intensity will be marked defective.
- All remaining 192 sub regions of interest are analyzed for defective pixels in the same manner.

Test Sub Regions of Interest

Pixel (1620,1220)

177         178         179         180         181         182         183         184         185         186         187         188         189         190         191         192           161         162         163         164         165         166         167         168         169         170         171         172         173         174         175         176           145         146         147         148         149         150         151         152         153         154         155         156         157         158         159         160           129         130         131         132         133         134         135         136         137         138         139         140         141         142         143         144           113         114         115         116         117         118         119         120         121         122         123         124         125         126         127         128           97         98         99         100         101         102         103         104         105         106         107         108 <td< th=""><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th></th></td<>																
145       146       147       148       149       150       151       152       153       154       155       156       157       158       159       160         129       130       131       132       133       134       135       136       137       138       139       140       141       142       143       144         113       114       115       116       117       118       119       120       121       122       123       124       125       126       127       128         97       98       99       100       101       102       103       104       105       106       107       108       109       110       111       112         81       82       83       84       85       86       87       88       89       90       91       92       93       94       95       96         65       66       67       68       69       70       71       72       73       74       75       76       77       78       79       80         49       50       51       52       53       54       55 </td <td>177</td> <td>178</td> <td>179</td> <td>180</td> <td>181</td> <td>182</td> <td>183</td> <td>184</td> <td>185</td> <td>186</td> <td>187</td> <td>188</td> <td>189</td> <td>190</td> <td>191</td> <td>192</td>	177	178	179	180	181	182	183	184	185	186	187	188	189	190	191	192
129       130       131       132       133       134       135       136       137       138       139       140       141       142       143       144         113       114       115       116       117       118       119       120       121       122       123       124       125       126       127       128         97       98       99       100       101       102       103       104       105       106       107       108       109       110       111       112         81       82       83       84       85       86       87       88       89       90       91       92       93       94       95       96         65       66       67       68       69       70       71       72       73       74       75       76       77       78       79       80         49       50       51       52       53       54       55       56       57       58       59       60       61       62       63       64         33       34       35       36       37       38       39       40	161	162	163	164	165	166	167	168	169	170	171	172	173	174	175	176
113       114       115       116       117       118       119       120       121       122       123       124       125       126       127       128         97       98       99       100       101       102       103       104       105       106       107       108       109       110       111       112         81       82       83       84       85       86       87       88       89       90       91       92       93       94       95       96         65       66       67       68       69       70       71       72       73       74       75       76       77       78       79       80         49       50       51       52       53       54       55       56       57       58       59       60       61       62       63       64         33       34       35       36       37       38       39       40       41       42       43       44       45       46       47       48         17       18       19       20       21       22       23       24	145	146	147	148	149	150	151	152	153	154	155	156	157	158	159	160
97       98       99       100       101       102       103       104       105       106       107       108       109       110       111       112         81       82       83       84       85       86       87       88       89       90       91       92       93       94       95       96         65       66       67       68       69       70       71       72       73       74       75       76       77       78       79       80         49       50       51       52       53       54       55       56       57       58       59       60       61       62       63       64         33       34       35       36       37       38       39       40       41       42       43       44       45       46       47       48         17       18       19       20       21       22       23       24       25       26       27       28       29       30       31       32	129	130	131	132	133	134	135	136	137	138	139	140	141	142	143	144
81     82     83     84     85     86     87     88     89     90     91     92     93     94     95     96       65     66     67     68     69     70     71     72     73     74     75     76     77     78     79     80       49     50     51     52     53     54     55     56     57     58     59     60     61     62     63     64       33     34     35     36     37     38     39     40     41     42     43     44     45     46     47     48       17     18     19     20     21     22     23     24     25     26     27     28     29     30     31     32	113	114	115	116	117	118	119	120	121	122	123	124	125	126	127	128
65     66     67     68     69     70     71     72     73     74     75     76     77     78     79     80       49     50     51     52     53     54     55     56     57     58     59     60     61     62     63     64       33     34     35     36     37     38     39     40     41     42     43     44     45     46     47     48       17     18     19     20     21     22     23     24     25     26     27     28     29     30     31     32	97	98	99	100	101	102	103	104	105	106	107	108	109	110	111	112
49     50     51     52     53     54     55     56     57     58     59     60     61     62     63     64       33     34     35     36     37     38     39     40     41     42     43     44     45     46     47     48       17     18     19     20     21     22     23     24     25     26     27     28     29     30     31     32	81	82	83	84	85	86	87	88	89	90	91	92	93	94	95	96
33     34     35     36     37     38     39     40     41     42     43     44     45     46     47     48       17     18     19     20     21     22     23     24     25     26     27     28     29     30     31     32	65	66	67	68	69	70	71	72	73	74	75	76	77	78	79	80
17     18     19     20     21     22     23     24     25     26     27     28     29     30     31     32	49	50	51	52	53	54	55	56	57	58	59	60	61	62	63	64
	33	34	35	36	37	38	39	40	41	42	43	44	45	46	47	48
1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16	17	18	19	20	21	22	23	24	25	26	27	28	29	30	31	32
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16

Pixel (21,21)

VOUTa ◀

Figure 14. Test Sub Regions of Interest

#### **OPERATION**

## **Absolute Maximum Ratings**

Absolute maximum rating is defined as a level or condition that should not be exceeded at any time per the

description. If the level or the condition is exceeded, the device will be degraded and may be damaged. Operation at these values will reduce MTTF.

**Table 12. ABSOLUTE MAXIMUM RATINGS** 

Description	Symbol	Minimum	Maximum	Unit	Notes
Operating Temperature	T <sub>OP</sub>	-50	70	°C	1
Humidity	RH	5	90	%	2
Output Bias Current	I <sub>OUT</sub>	-	60	mA	3
Off-Chip Load	C <sub>L</sub>	-	10	pF	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Noise performance will degrade at higher temperatures.
- 2. T = 25°C. Excessive humidity will degrade MTTF.
- 3. Total for all outputs. Maximum current is -15 mA for each output. Avoid shorting output pins to ground or any low impedance source during operation. Amplifier bandwidth increases at higher current and lower load capacitance at the expense of reduced gain (sensitivity).

Table 13. ABSOLUTE MAXIMUM VOLTAGE RATINGS BETWEEN PINS AND GROUND

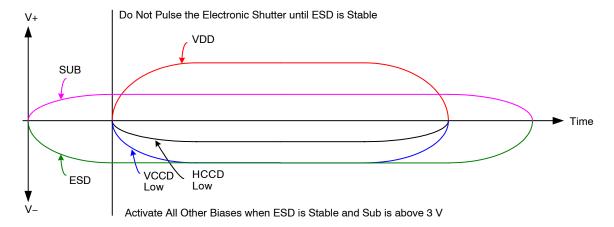
Description	Minimum	Maximum	Unit	Notes
VDDα, VOUΤα	-0.4	17.5	V	1
RDα	-0.4	15.5	V	1
V1B, V1T	ESD - 0.4	ESD + 24.0	V	
V2B, V2T, V3B, V3T, V4B, V4T	ESD - 0.4	ESD + 14.0	V	
H1Sα, H1Bα, H2Sα, H2Bα, H2SLα, Rα, OGα	ESD - 0.4	ESD + 14.0	V	1
ESD	-10.0	0.0	V	
SUB	-0.4	40.0	V	2

<sup>1.</sup> α denotes a, b, c or d.

<sup>2.</sup> Refer to Application Note Using Interline CCD Image Sensors in High Intensity Visible Lighting Conditions

#### Power-Up and Power-Down Sequence

Adherence to the power-up and power-down sequence is critical. Failure to follow the proper power-up and power-down sequences may cause damage to the sensor.



#### Notes:

- 1. Activate all other biases when ESD is stable and SUB is above 3 V.
- 2. Do not pulse the electronic shutter until ESD is stable.
- 3. VDD cannot be  $+15\ V$  when SUB is 0 V.
- 4. The image sensor can be protected from an accidental improper ESD voltage by current limiting the SUB current to less than 10 mA. SUB and VDD must always be greater than GND. ESD must always be less than GND. Placing diodes between SUB, VDD, ESD and ground will protect the sensor from accidental overshoots of SUB, VDD and ESD during power on and power off. See the figure below.

Figure 15. Power-Up and Power-Down Sequence

The VCCD clock waveform must not have a negative overshoot more than 0.4 V below the ESD voltage.

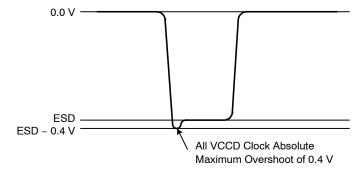


Figure 16. VCCD Clock Waveform

Example of external diode protection for SUB, VDD and ESD. $\alpha$  denotes a, b, c or d.

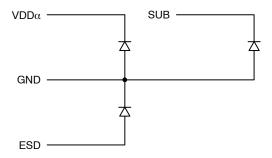


Figure 17. Example of External Diode Protection

#### **DC Bias Operating Conditions**

**Table 14. DC BIAS OPERATING CONDITIONS** 

Description	Pins	Symbol	Min.	Nom.	Max.	Unit	Max. DC Current	Notes
Reset Drain	RDα	RD	11.8	12.0	12.2	V	10 μΑ	1
Output Gate	OGα	OG	-2.2	-2.0	-1.8	V	10 μΑ	1
Output Amplifier Supply	VDDα	$V_{DD}$	14.5	15.0	15.5	V	11.0 mA	1, 2
Ground	GND	GND	0.0	0.0	0.0	V	–1.0 mA	
Substrate	SUB	V <sub>SUB</sub>	5.0	$V_{AB}$	$V_{DD}$	V	50 μΑ	3, 8
ESD Protection Disable	ESD	ESD	-9.5	-9.0	Vx_L	V	50 μΑ	6, 7, 9
Output Bias Current	VOUTα	I <sub>OUT</sub>	-3.0	-7.0	-10.0	mA	-	1, 4, 5

- 1.  $\alpha$  denotes a, b, c or d.
- The maximum DC current is for one output. I<sub>DD</sub> = I<sub>OUT</sub> + I<sub>SS</sub>. See Figure 18.
   The operating value of the substrate voltage, V<sub>AB</sub>, will be marked on the shipping container for each device. The value of V<sub>AB</sub> is set such that the photodiode charge capacity is the nominal P<sub>Ne</sub> (see Specifications).

  4. An output load sink must be applied to each VOUT pin to activate each output amplifier.
- 5. Nominal value required for 40 MHz operation per output. May be reduced for slower data rates and lower noise.
- Adherence to the power-up and power-down sequence is critical. See Power Up and Power Down Sequence section.
   ESD maximum value must be less than or equal to V1\_L + 0.4 V and V2\_L + 0.4 V.
- Refer to Application Note *Using Interline CCD Image Sensors in High Intensity Visible Lighting Conditions*.
   Where Vx\_L is the level set for V1\_L, V2\_L, V3\_L, or V4\_L in the application.

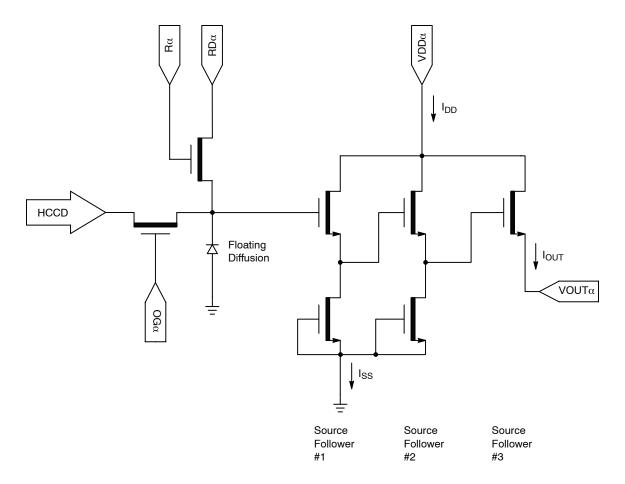


Figure 18. Output Amplifier

## **AC Operating Conditions**

#### **Table 15. CLOCK LEVELS**

Description	Pins (Note 1)	Symbol	Level	Min.	Nom.	Max.	Unit	Capacitance (Note 2)
Vertical CCD Clock, Phase 1	V1B, V1T	V1_L	Low	-8.2	-8.0	-7.8	V	11 nF
		V1_M	Mid	-0.2	0.0	0.2		(Note 6)
		V1_H	High	11.5	12.0	12.5		
Vertical CCD Clock, Phase 2	V2B, V2T	V2_L	Low	-8.2	-8.0	-7.8	V	11 nF
		V2_H	High	-0.2	0.0	0.2		(Note 6)
Vertical CCD Clock, Phase 3	V3B, V3T	V3_L	Low	-8.2	-8.0	-7.8	V	11 nF
		V3_H	High	-0.2	0.0	0.2		(Note 6)
Vertical CCD Clock, Phase 4	V4B, V4T	V4_L	Low	-8.2	-8.0	-7.8	V	11 nF
		V4_H	High	-0.2	0.0	0.2		(Note 6)
Horizontal CCD Clock, Phase 1 Storage	H1Sα	H1S_L	Low	-5.2 (Note 7)	-4.0	-3.8	V	140 pF (Note 6)
		H1S_A	Amplitude	3.8	4.0	5.2 (Note 7)		
Horizontal CCD Clock, Phase 1 Barrier	Η1Βα	H1B_L	Low	-5.2 (Note 7)	-4.0	-3.8	V	93 pF (Note 6)
		H1B_A	Amplitude	3.8	4.0	5.2 (Note 7)		
Horizontal CCD Clock, Phase 2 Storage	H2Sα	H2S_L	Low	-5.2 (Note 7)	-4.0	-3.8	V	140 pF (Note 6)
		H2S_A	Amplitude	3.8	4.0	5.2 (Note 7)		
Horizontal CCD Clock, Phase 2 Barrier	Н2Вα	H2B_L	Low	-5.2 (Note 7)	-4.0	-3.8	V	93 pF (Note 6)
		H2B_A	Amplitude	3.8	4.0	5.2 (Note 7)		
Horizontal CCD Clock,	H2SLα	H2SL_L	Low	-5.2	-5.0	-4.8	V	20 pF
Phase 2 Last Phase (Note 3)		H2SL_A	Amplitude	4.8	5.0	5.2		(Note 6)
Reset Gate	Rα	R_L (Note 4)	Low	-3.5	-2.0	-1.5	V	16 pF (Note 6)
		R_H	High	2.5	3.0	4.0		
Electronic Shutter (Note 5)	SUB	VES	High	29.0	30.0	40.0	V	700 pF (Note 6)

<sup>1.</sup>  $\alpha$  denotes a, b, c or d.

<sup>2.</sup> Capacitance is total for all like named pins.

Use separate clock driver for improved speed performance.
 Reset low should be set to -3 V for signal levels greater than 40,000 electrons.

Refer to Application Note *Using Interline CCD Image Sensors in High Intensity Visible Lighting Conditions*.
 Capacitance values are estimated.

<sup>7.</sup> If the minimum horizontal clock low level is used (–5.2 V), then the maximum horizontal clock amplitude should be used (5.2 V amplitude) to create a –5.2 V to 0.0 V clock. If a 5 V clock driver is used, the horizontal low level should be set to –5.0 V and the high level should be a set to 0.0 V.

The figure below shows the DC bias (VSUB) and AC clock (VES) applied to the SUB pin. Both the DC bias and AC clock are referenced to ground.

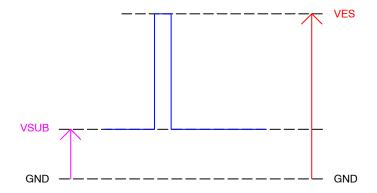


Figure 19. DC Bias and AC Clock Applied to the SUB Pin

#### **Device Identification**

The device identification pin (DevID) may be used to determine which 5.5 micron pixel interline CCD sensor is being used.

Table 16.

Description	Pins	Symbol	Min.	Nom.	Max.	Unit	Max. DC Current	Notes
Device Identification	DevID	DevID	86,000	108,000	130,000	Ω	50 μA	1, 2, 3

- 1. Nominal value subject to verification and/or change during release of preliminary specifications.
- 2. If the Device Identification is not used, it may be left disconnected.
- 3. After Device Identification resistance has been read during camera initialization, it is recommended that the circuit be disabled to prevent localized heating of the sensor due to current flow through the R DeviceID resistor.

#### Recommended Circuit

Note that V1 must be a different value than V2.

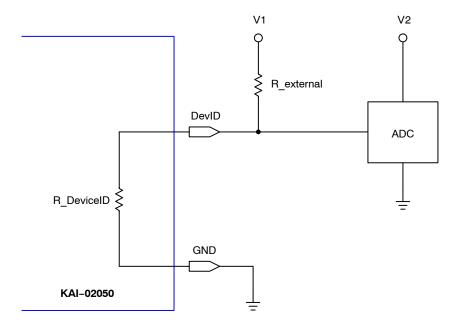


Figure 20. Device Identification Recommended Circuit

## **TIMING**

Table 17. REQUIREMENTS AND CHARACTERISTICS (Note 1)

Description	Symbol	Min.	Nom.	Max.	Unit	Notes
Photodiode Transfer	t <sub>PD</sub>	1.0	-	-	μs	
VCCD Leading Pedestal	t <sub>3P</sub>	4.0	-	-	μs	
VCCD Trailing Pedestal	t <sub>3D</sub>	4.0	-	-	μs	
VCCD Transfer Delay	t <sub>D</sub>	1.0	-	-	μs	
VCCD Transfer	t <sub>V</sub>	1.0	_	-	μs	
VCCD Clock Cross-Over	V <sub>VCR</sub>	75	_	100	%	
VCCD Rise, Fall Times	$t_{VR}, t_{VF}$	5	_	10	%	2, 3
HCCD Delay	t <sub>HS</sub>	0.2	_	-	μs	
HCCD Transfer	t <sub>e</sub>	25.0	_	-	ns	
Shutter Transfer	t <sub>SUB</sub>	1.0	_	-	μs	
Shutter Delay	t <sub>HD</sub>	1.0	-	-	μs	
Reset Pulse	t <sub>R</sub>	2.5	-	-	ns	
Reset - Video Delay	t <sub>RV</sub>	-	2.2	-	ns	
H2SL - Video Delay	t <sub>HV</sub>	-	3.1	-	ns	
Line Time	t <sub>LINE</sub>	23.0	_	-	μs	Dual HCCD Readout
		44.1	_	-	μs	Single HCCD Readout
Frame Time	t <sub>FRAME</sub>	14.6	_	-	ms	Quad HCCD Readout
		29.1	-	-	ms	Dual HCCD Readout
		55.7	-	-	ms	Single HCCD Readout

Refer to timing diagrams as shown in Figure 21, Figure 22, Figure 23, Figure 24 and Figure 25.
 Refer to Figure 25: VCCD Clock Edge Alignment.
 Relative to the pulse width.

## **Timing Diagrams**

The timing sequence for the clocked device pins may be represented as one of seven patterns (P1-P7) as shown in the table below. The patterns are defined in Figure 21 and

Figure 22. Contact ON Semiconductor Application Engineering for other readout modes.

**Table 18. TIMING DIAGRAMS** 

Device Pin	Quad Readout	Dual Readout VOUTa, VOUTb	Dual Readout VOUTa, VOUTc	Single Readout VOUTa							
V1T	P1T	P1B	P1T	P1B							
V2T	P2T	P4B	P2T	P4B							
V3T	P3T	P3B	P3T	P3B							
V4T	P4T	P2B	P4T	P2B							
V1B		P	1B								
V2B		P	2B								
V3B		P:	3B								
V4B	P4B										
H1Sa		P5									
H1Ba		P5									
H2Sa (Note 2)	P6										
H2Ba	P6										
Ra	P7										
H1Sb		P5	F	25							
H1Bb		P5	F	26							
H2Sb (Note 2)		P6	F	26							
H2Bb		P6	P5								
Rb		P7	P7 (Note 1) or Off (Note 3)	P7 (Note 1) or Off (Note 3							
H1Sc	P5	P5 (Note 1) or Off (Note 3)	P5	P5 (Note 1) or Off (Note 3							
H1Bc	P5	P5 (Note 1) or Off (Note 3)	P5	P5 (Note 1) or Off (Note 3							
H2Sc (Note 2)	P6	P6 (Note 1) or Off (Note 3)	P6	P6 (Note 1) or Off (Note 3							
H2Bc	P6	P6 (Note 1) or Off (Note 3)	P6	P6 (Note 1) or Off (Note 3							
Rc	P7	P7 (Note 1) or Off (Note 3)	P7	P7 (Note 1) or Off (Note 3							
H1Sd	P5	P5 (Note 1) or Off (Note 3)	P5	P5 (Note 1) or Off (Note 3							
H1Bd	P5	P5 (Note 1) or Off (Note 3)	P6	P5 (Note 1) or Off (Note 3							
H2Sd (Note 2)	P6	P6 (Note 1) or Off (Note 3)	P6	P6 (Note 1) or Off (Note 3							
H2Bd	P6	P6 (Note 1) or Off (Note 3)	P5	P6 (Note 1) or Off (Note 3							
Rd	P7	P7 (Note 1) or Off (Note 3)	P7 (Note 1) or Off (Note 3)	P7 (Note 1) or Off (Note 3							

#Lines/Frame (Minimum)	632	1264	632	1264		
#Pixels/Line (Minimum)	853		1706			

<sup>1.</sup> For optimal performance of the sensor. May be clocked at a lower frequency. If clocked at a lower frequency, the frequency selected should be a multiple of the frequency used on the a and b register.

<sup>2.</sup> H2SLx follows the same pattern as H2Sx For optimal speed performance, use a separate clock driver.

<sup>3.</sup> Off = +5 V. Note that there may be operating conditions (high temperature and/or very bright light sources) that will cause blooming from the unused c/d register into the image area.

#### Photodiode Transfer Timing

A row of charge is transferred to the HCCD on the falling edge of V1 as indicated in the P1 pattern below. Using this timing sequence, the leading dummy row or line is combined with the first dark row in the HCCD. The "Last Line" is dependent on readout mode – either 632 or 1264 minimum counts required. It is important to note that, in

general, the rising edge of a vertical clock (patterns P1–P4) should be coincident or slightly leading a falling edge at the same time interval. This is particularly true at the point where P1 returns from the high (3<sup>rd</sup> level) state to the mid-state when P4 transitions from the low state to the high state.

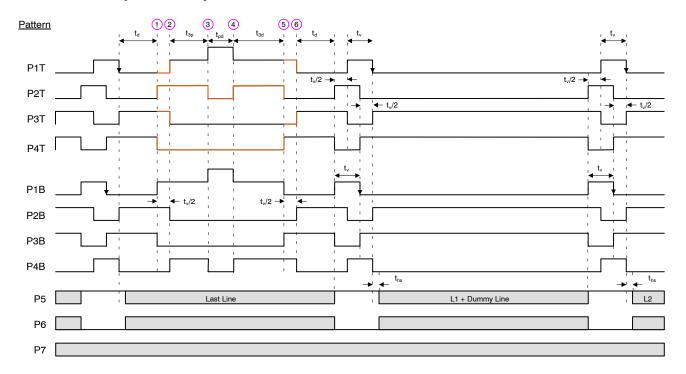


Figure 21. Photodiode Transfer Timing

## Line and Pixel Timing

Each row of charge is transferred to the output, as illustrated below, on the falling edge of H2SL (indicated as

P6 pattern). The number of pixels in a row is dependent on readout mode – either 853 or 1706 minimum counts required.

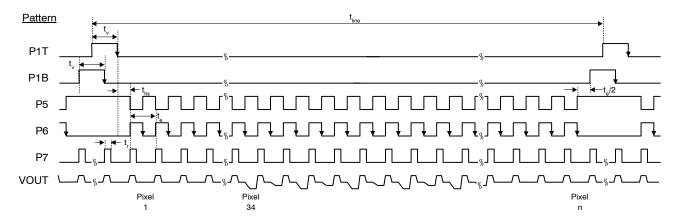


Figure 22. Line and Pixel Timing

## Pixel Timing Detail

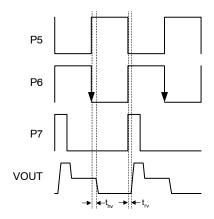


Figure 23. Pixel Timing Detail

## Frame/Electronic Shutter Timing

The SUB pin may be optionally clocked to provide electronic shuttering capability as shown below. The

resulting photodiode integration time is defined from the falling edge of SUB to the falling edge of V1 (P1 pattern).

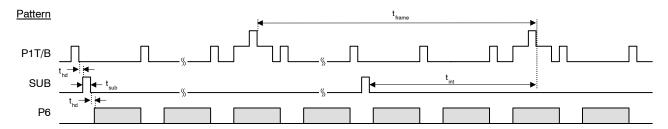


Figure 24. Frame/Electronic Shutter Timing

## VCCD Clock Edge Alignment

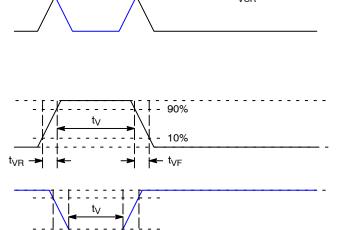


Figure 25. VCCD Clock Edge Alignment

Line and Pixel Timing – Vertical Binning by 2

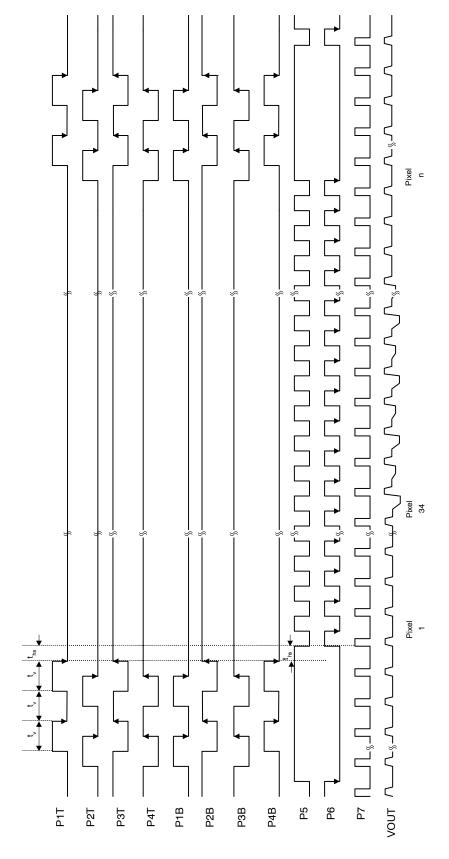


Figure 26. Line and Pixel Timing – Vertical Binning by 2

#### STORAGE AND HANDLING

**Table 19. STORAGE CONDITIONS** 

Description	Symbol	Minimum	Maximum	Unit	Notes
Storage Temperature	T <sub>ST</sub>	-55	80	°C	1
Humidity	RH	5	90	%	2

<sup>1.</sup> Long-term storage toward the maximum temperature will accelerate color filter degradation.

For information on ESD and cover glass care and cleanliness, please download the *Image Sensor Handling and Best Practices* Application Note (AN52561/D) from www.onsemi.com.

For information on environmental exposure, please download the *Using Interline CCD Image Sensors in High Intensity Lighting Conditions* Application Note (AND9183/D) from <a href="https://www.onsemi.com">www.onsemi.com</a>.

For information on soldering recommendations, please download the Soldering and Mounting Techniques Reference Manual (SOLDERRM/D) from www.onsemi.com.

For quality and reliability information, please download the *Quality & Reliability* Handbook (HBD851/D) from www.onsemi.com.

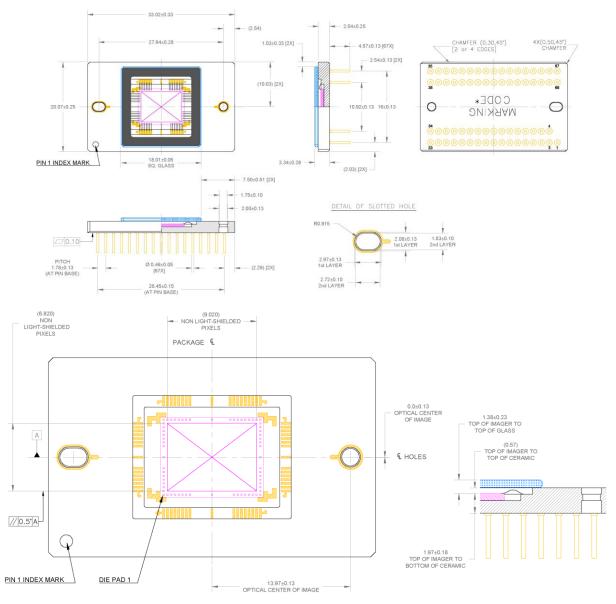
For information on device numbering and ordering codes, please download the *Device Nomenclature* technical note (TND310/D) from <a href="https://www.onsemi.com">www.onsemi.com</a>.

For information on Standard terms and Conditions of Sale, please download <u>Terms and Conditions</u> from <u>www.onsemi.com</u>.

<sup>2.</sup> T = 25°C. Excessive humidity will degrade MTTF.

#### **MECHANICAL INFORMATION**

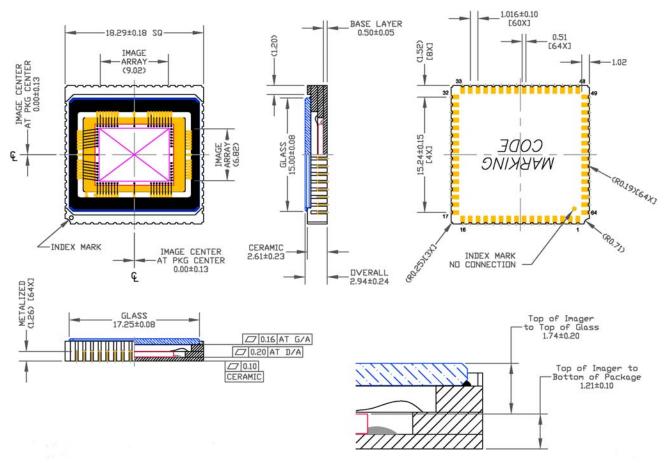
## **PGA Completed Assembly**



- 1. See Ordering Information for marking code.
- 2. No materials to interfere with clearance through guide holes.
- 3. The center of the active image is nominally at the center of the package.
- 4. Die rotation < 0.5 degrees.
- 5. Glass rotation < 1.5 degrees with respect to package outer edges for all sealed configurations.
- 6. Internal traces may be exposed on sides of package. Do not allow metal to contact sides of ceramic package.
- 7. Recommended mounting screws:1.6 × 0.35 mm (ISO Standard); 0–80 (Unified Fine Thread Standard).
- 8. Units: millimeters.

Figure 27. PGA Completed Assembly

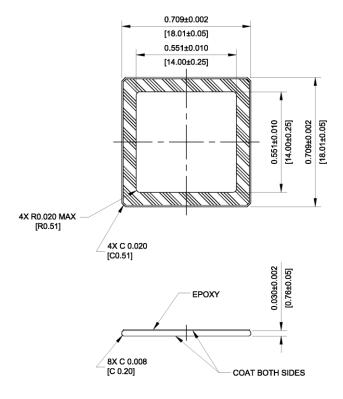
## **CLCC Completed Assembly**



- 1. See Ordering Information for marking code.
- 2. Die rotation < 0.5 degrees.
- 3. Units: millimeters.

Figure 28. CLCC Completed Assembly

## **PGA MAR Cover Glass**

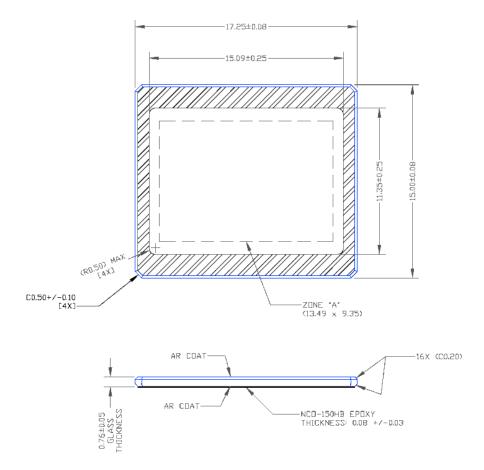


- 1. Dust/Scratch Count 12 micron maximum
- Units: IN [MM]
   Reflectance Specification
   a. 420 nm to 435 nm < 2.0%

  - b. 435 nm to 630 nm < 0.8%
  - c. 630 nm to 680 nm < 2.0%

Figure 29. PGA MAR Cover Glass

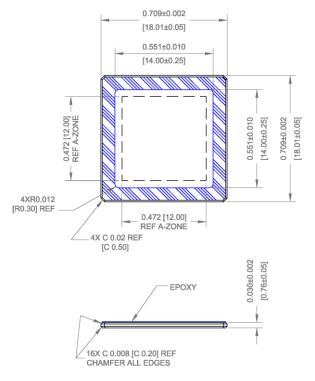
## **CLCC MAR Cover Glass**



- 1. Dust/Scratch Count 12 micron maximum
- 2. Units: millimeter
- 3. Reflectance Specification
  - a. 420 nm to 435 nm < 2.0%
  - b. 435 nm to 630 nm < 0.8% c. 630 nm to 680 nm < 2.0%

Figure 30. CLCC MAR Cover Glass

## **PGA Clear Cover Glass**

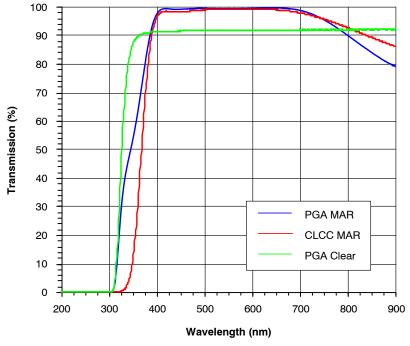


#### Notes:

- 1. Dust/Scratch Count 12 micron maximum
- 2. Units: IN

Figure 31. PGA Clear Cover Glass

## **Cover Glass Transmission**



NOTE: PGA and CLCC MAR transmission data differ due to in-spec differences from glass vendor.

Figure 32. Cover Glass Transmission

## **SHIPPING CONFIGURATION**

## **Cover Glass Protective Tape**

Cover glass protective tape, as shown in Figure 33, is utilized to help ensure the cleanliness of the cover glass during transportation and camera manufacturing. This protective tape is not intended to be optically correct, and

should be removed prior to any image testing. The protective tape should be removed in an ionized air stream to prevent static build-up and the attraction of particles. The following part numbers will have the protective tape applied:

#### Table 20.

Part Number	Description
KAI-02050-CBA-JB-B2	Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2
KAI-02050-CBA-JB-AE	Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Engineering Grade
KAI-02050-CBA-JB-B2-T	Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2, Packed in Trays

#### Table 21.

Criteria	Description
Placement	Per the drawing. The lid tape shall not overhang the edge of the package or mounting holes. The lid tape always overhangs the top of the glass (chamfers not included).
Tab Location	The tape tab is located near pin 68.
Scratches	The tape application equipment will make slight scratches on the lid tape. This is allowed.

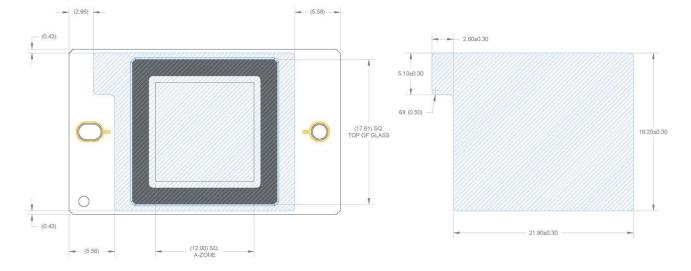


Figure 33. Cover Glass Protective Tape

## **Tray Packing**

The following part numbers are packed in bricks of 6 trays, each tray containing 32 image sensors, for a total of

192 image sensors per brick. The minimum order and multiple quantities for this configuration are 192 image sensors.

Table 22.

Part Number	Description
KAI-02050-CBA-JB-B2-T	Color (Bayer RGB), Telecentric Microlens, PGA Package, Sealed Clear Cover Glass (No Coatings), Grade 2, Packed in Trays

## Tray Configuration

## Pin-Up View

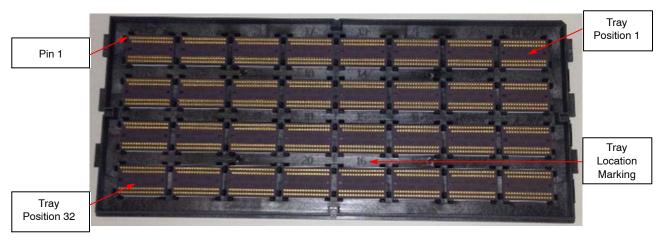


Figure 34. Tray Pin-Up View

## Pin-Down View



Figure 35. Tray Pin-Down View

## **Brick Configuration**

Bricks consist of 6 full trays and 1 empty tray. Each tray contains 32 image sensors. There are a total of 192 image

sensors in the brick. The ID label is applied to the top of the brick. Tray 1 is at the bottom of the brick and the empty tray is at the top of the brick.

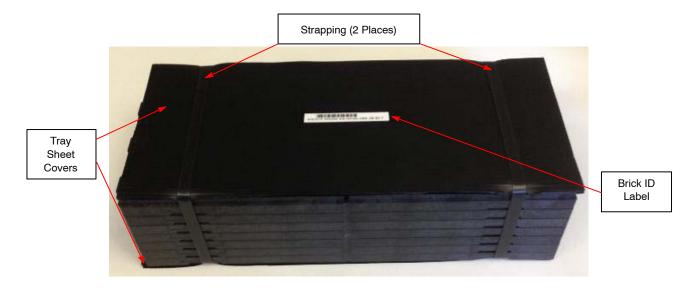


Figure 36. Brick

The Brick ID is Encoded in the Bar Code.



Figure 37. Brick ID Label

Brick in Vacuum Sealed Bag



Figure 38. Sealed Brick

## Shipping Container

## Brick Loaded in Shipping Container



Figure 39. Brick Loaded in Shipping Container

## Open Shipping Container with Parts List

The parts list (see Figure 43) details information for each sensor in the brick. The parts list includes the serial number, tray and location, and VAB value for each sensor.



Figure 40. Open Shipping Container with Parts List

## Sealed Shipping Container

The Brick Label (see Figure 42) is applied to both ends of the shipping container.



Figure 41. Sealed Shipping Container

#### **Brick Label**

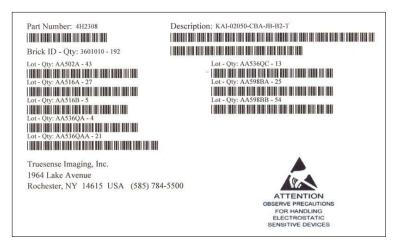


Figure 42. Brick Label

#### Parts List

The parts list details information for each sensor in the brick. The parts list includes the serial number, tray and location, and VAB value for each sensor. Additionally, the VAB value and serial number are encoded in the bar code.

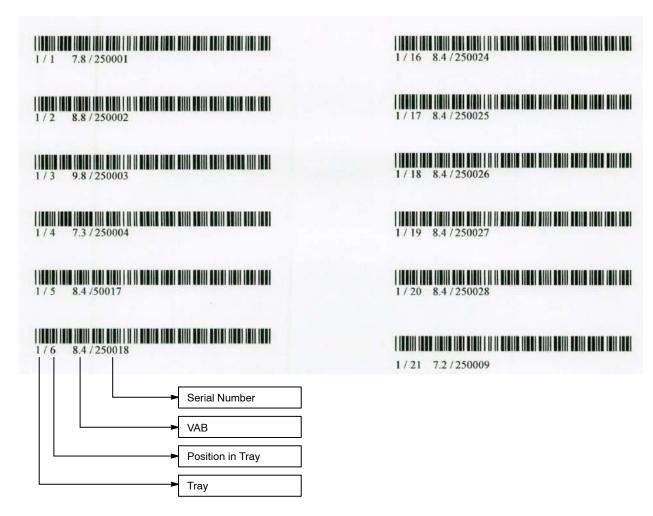


Figure 43. Parts List

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